

Aberration budget based on Zernike sensitivity for EUV lithography

○Yumi Nakajima, Takashi Sato, Ryoichi Inanami,
Tatsuhiko Higashiki
Process & Manufacturing Engineering Center,
Semiconductor Company, Toshiba Corporation

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6. Conclusions

1-1. Motivation

EUV lithography will start
at 22 nm node devices.

1st generation EUV (NA 0.25, 2009~)

Is it possible to form 22 nm node devices?

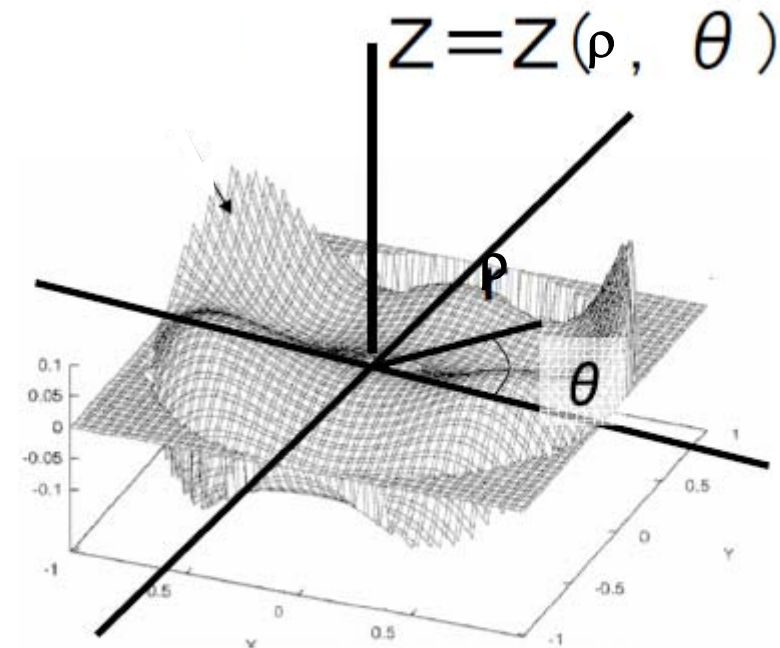
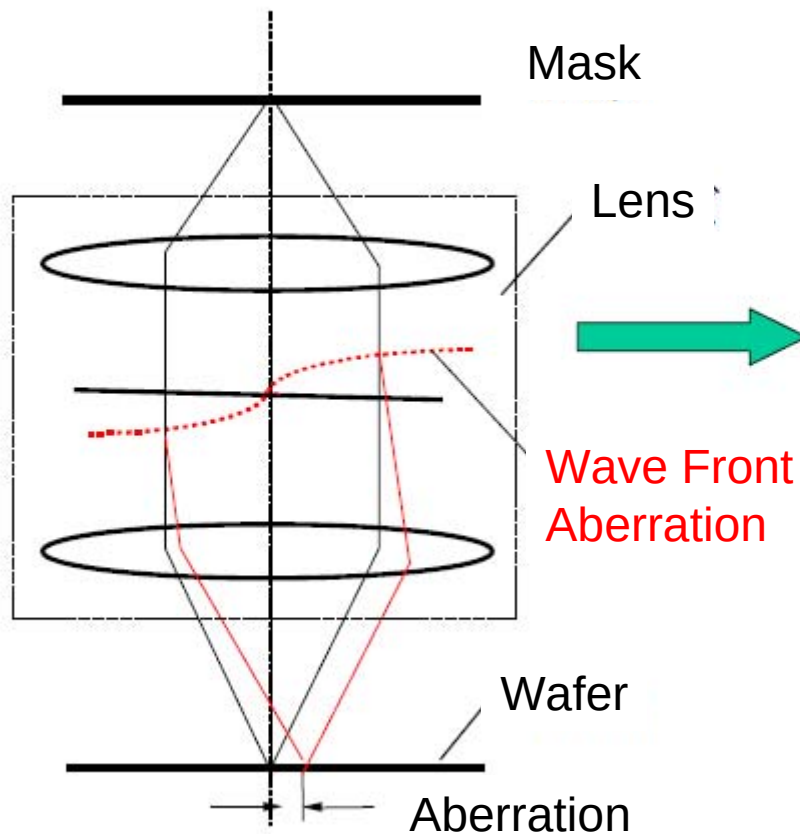
Key Points are the controllability of the aberration and the flare

22 nm dual-gate pattern needs high degree of accuracy in CD and position.

In this study, we estimate the aberration permissible for 22 nm dual-gate pattern using Zernike sensitivity based Design of Experimental (DOE) method.

1-2. Zernike polynomials

Wave front aberration



$$W(x_0, \rho, \theta) = \sum_m C_m(x_0) \cdot Z_m(\rho, \theta)$$

m : Integer > 0 ,
 C_m : Aberration coefficient,
 Z_m : Zernike polynomials

2-1. Calculation

Calculation Condition

- Simulator : Solid-EUV
- Wavelength : 13.5 nm
- NA : 0.25
- Illumination : Circle
- Sigma : 0.7
- Flare : 8% (Constant)

※ Calculated using aerial image

Two-bars (Dual-gate)



L/S = 22/22 nm

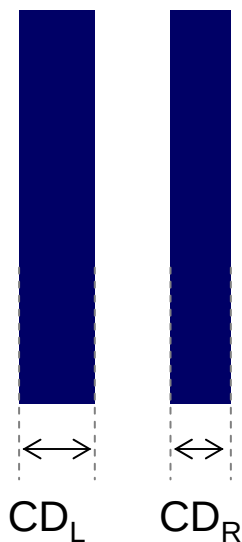
L/S = 22/22 nm



Thin mask

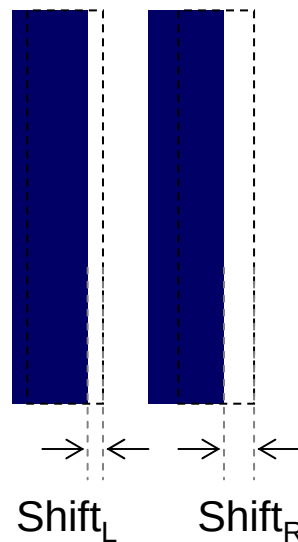
2-2. Requirements of 22 nm Two-bars

CD difference
between left and right



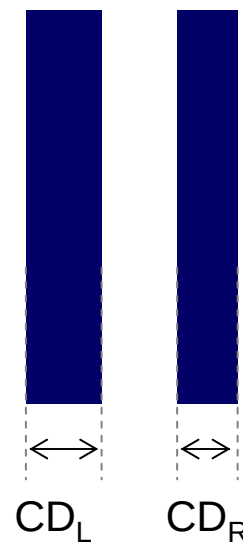
$$\text{CD difference} = CD_R - CD_L$$
$$< 2.2 \text{ nm}$$

Positional shift



$$\text{Shift}_L < 2.2 \text{ nm}$$
$$\text{Shift}_R < 2.2 \text{ nm}$$

CD error

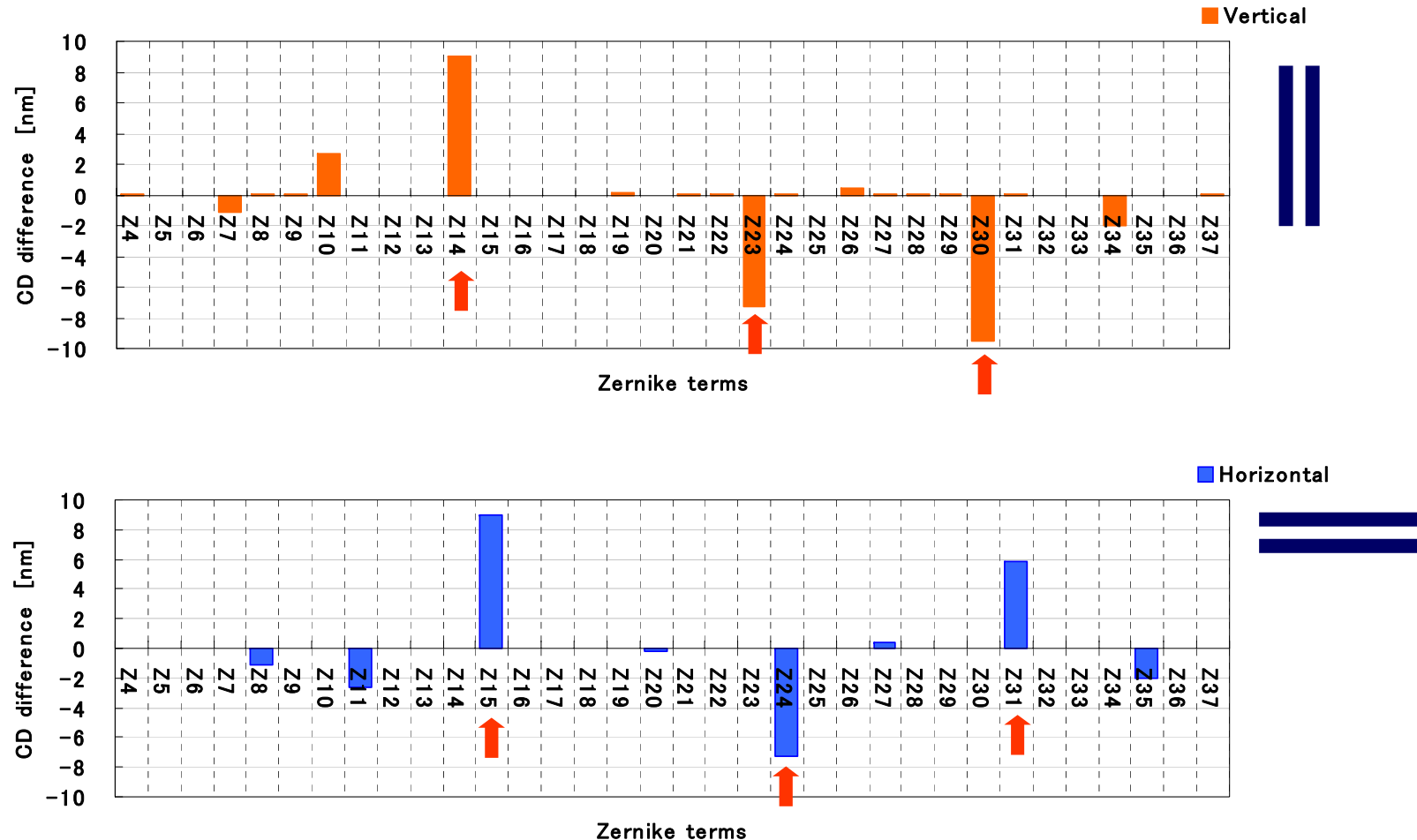


$$CD_L = 22 \text{ nm} \pm 2.2 \text{ nm}$$
$$CD_R = 22 \text{ nm} \pm 2.2 \text{ nm}$$

10% of target CD = 2.2 nm

3-1. CD difference of the two-bars

1. Zernike sensitivity (in the presence of 100 mλ rms)



Z14, Z23 and Z30 greatly affect on vertical two lines, and Z15, Z24 and Z31 affect on horizontal two lines.

3-1. CD difference of the two-bars

2. Calculated Effectiveness of each term

We calculated effectiveness of three Zernike terms using Design of Experimental (DOE).

$$\begin{aligned}\text{Total CD difference} = & A \cdot a_{14} + B \cdot a_{23} + C \cdot a_{30} \\ & + AB \cdot a_{14}a_{23} + BC \cdot a_{23}a_{30} + AC \cdot a_{14}a_{30} \\ & + ABC \cdot a_{14}a_{23}a_{30} + \text{constant}\end{aligned}$$

A: Coefficient of Error by Z14

B: Coefficient of Error by Z23

C: Coefficient of Error by Z30

AB: Coefficient of Error by Interaction of Z14 and Z23

BC: Coefficient of Error by Interaction of Z23 and Z30

AC: Coefficient of Error by Interaction of Z14 and Z30

ABC: Coefficient of Error by Interaction of Z14 , Z23 and Z30

a_{14} : aberration of Z14

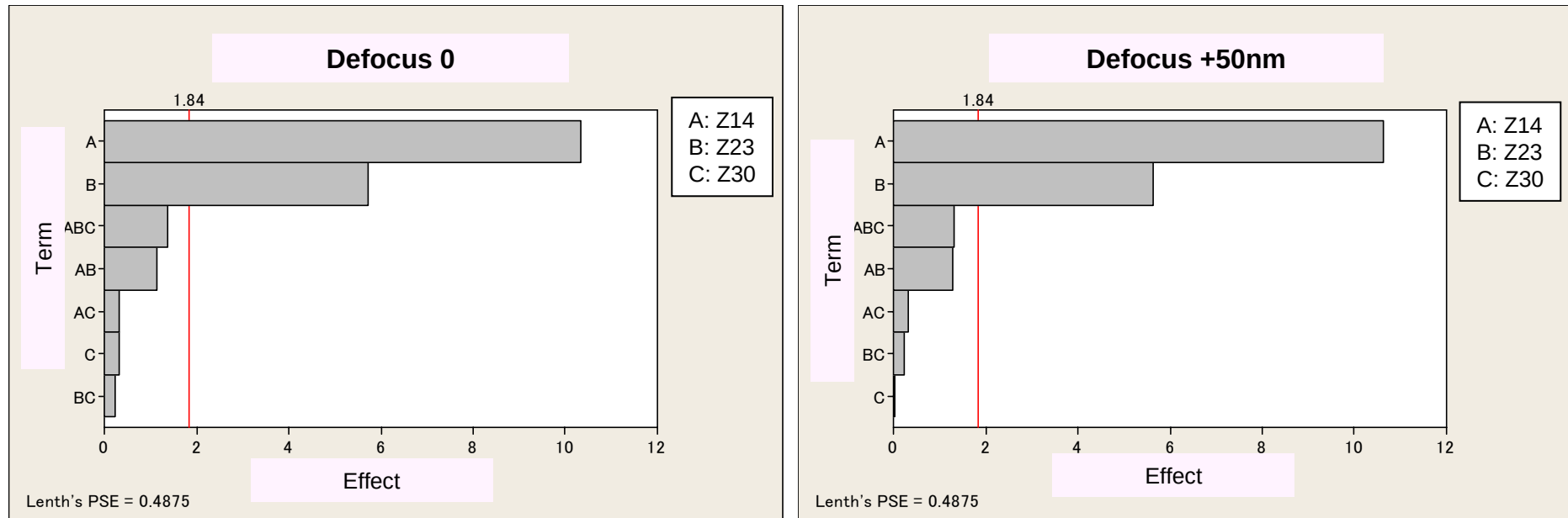
a_{23} : aberration of Z23

a_{30} : aberration of Z30

3-1. CD difference of the two-bars

2. Calculated Effectiveness of each term

Pareto Chart of the Effects

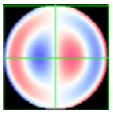
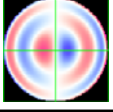
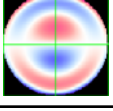
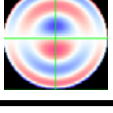


Z14 and Z23 occupy the greatly affect on CD difference of the two-bars

$$\text{Total CD error} \doteq A \cdot a_{14} + B \cdot a_{23} + \text{constant}$$

3-1. CD difference of the two-bars

3. Effective Zernike terms

Direction	terms	function	pupil image	aberration name
Vertical	Z14	$\sqrt{12} (10\rho^5 - 12\rho^3 + 3\rho)\cos\theta$		5 th order x-coma
	Z23	$\sqrt{16} (35\rho^7 - 60\rho^5 + 30\rho^3 + 4\rho)\cos\theta$		7 th order x-coma
Horizontal	Z15	$\sqrt{12} (10\rho^5 - 12\rho^3 + 3\rho)\sin\theta$		5 th order y-coma
	Z24	$\sqrt{16} (35\rho^7 - 60\rho^5 + 30\rho^3 + 4\rho)\sin\theta$		7 th order y-coma

The greatly affective aberrations on CD difference of the two-bar pattern are **Coma**.

3-1. CD difference of the two-bars

4. Results

Coefficient table

Term		defocus	
Vertical	Horizontal	0	+50 nm
A(Z14)	A(Z15)	0.103	0.106
B(Z23)	B(Z24)	0.057	0.056
Constant	Constant	-0.46	-0.54

$$\text{Total CD error} \doteq A \cdot a_{14} + B \cdot a_{23} + \text{constant}$$

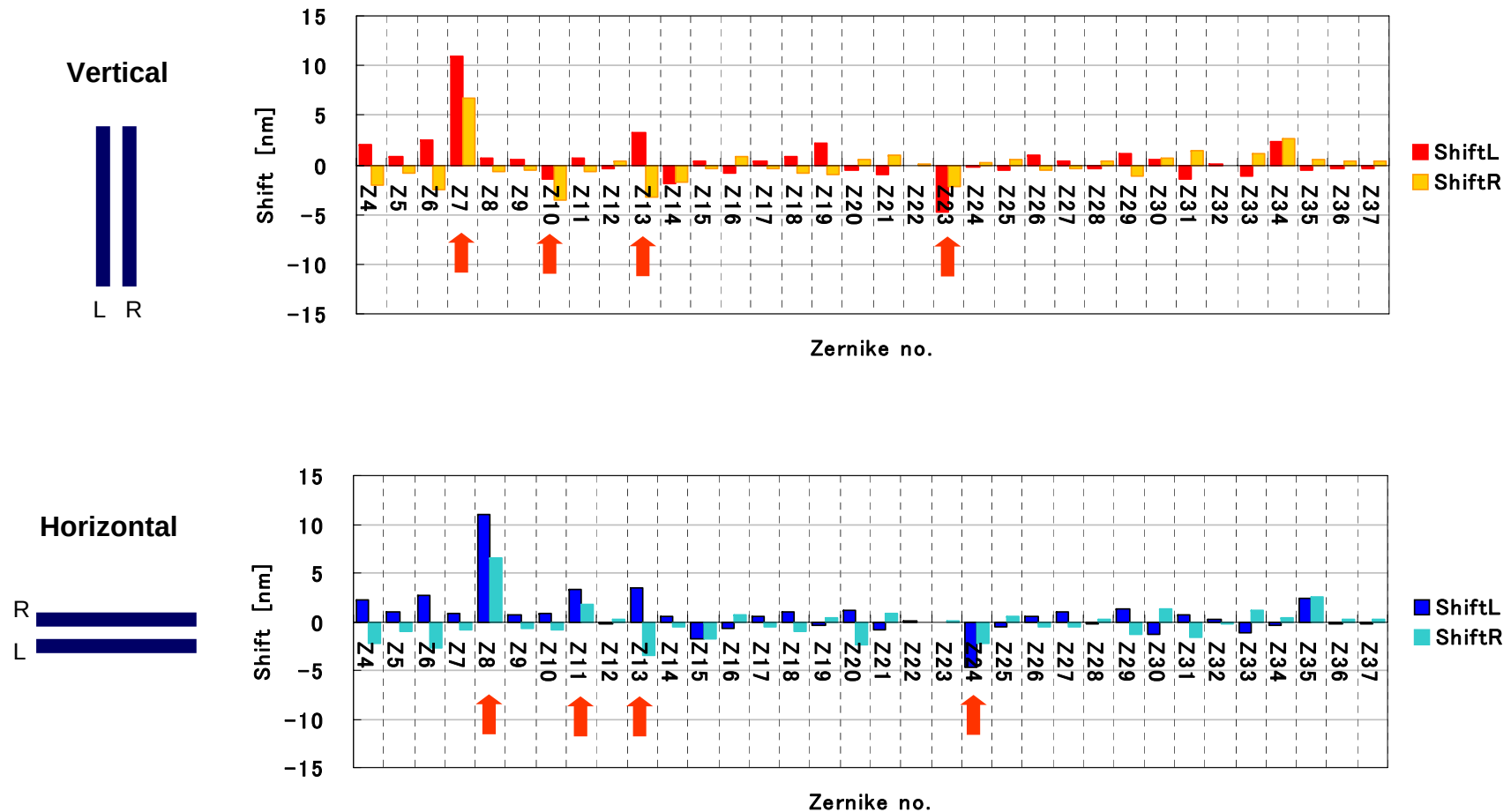
The aberration to control CD difference below 2.2 nm

defocus	
0	+50nm
25	24

[mλ rms]

3-2. Positional shift

1. Zernike sensitivity (in the presence of 100 mλ rms)

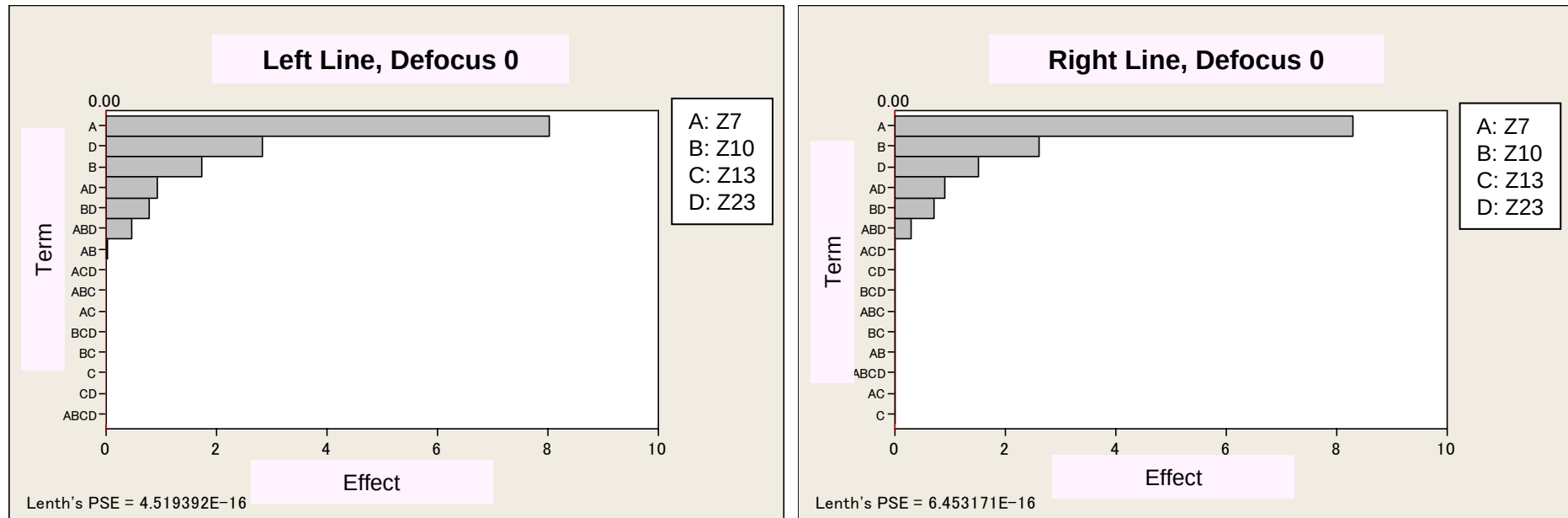


Z7, Z10, Z13 and Z23 greatly affect on vertical two lines, and Z8, Z11, Z13 and Z24 affect on horizontal two lines.

3-2. Positional shift

2. Calculated Effectiveness of each term

Pareto Chart of the Effects



Z7, Z10 and Z23 occupy the greatly affect on CD difference of the two-bars.

$$\text{Total Position shift} \doteq A \cdot a_7 + B \cdot a_{10} + D \cdot a_{23} + \text{constant}$$

3-2. Positional shift

3. Effective Zernike terms

Direction	terms	function	pupil image	aberration name
Vertical	Z7	$\sqrt{8} (3\rho^3 - 2\rho) \cos\theta$		3 th order x-coma
	Z10	$\sqrt{8} \rho^3 \cos 3\theta$		3-foil x
	Z23	$\sqrt{16} (35\rho^7 - 60\rho^5 + 30\rho^3 + 4\rho) \cos\theta$		7 th order x-coma
Horizontal	Z8	$\sqrt{8} (3\rho^3 - 2\rho) \sin\theta$		3 th order y-coma
	Z11	$\sqrt{8} \rho^3 \sin 3\theta$		3-foil y
	Z24	$\sqrt{16} (35\rho^7 - 60\rho^5 + 30\rho^3 + 4\rho) \sin\theta$		7 th order y-coma

Coma and **3-foil** aberrations influence to Positional shift.

3-2. Positional shift

4. Results

Coefficient table

Term		Left line		Right line	
Vertical	Horizontal	defocus		defocus	
		0	+50 nm	0	+50 nm
A(Z7)	A(Z8)	0.080	0.0853	0.083	0.0893
B(Z10)	B(Z11)	0.017	0.0163	0.026	0.0248
D(Z23)	D(Z24)	0.028	0.0318	0.015	0.0183
Constant	Constant	1.163	1.388	-1.15	-1.363

$$\text{Total Position shift} \doteq A \cdot a_7 + B \cdot a_{10} + D \cdot a_{23} + \text{constant}$$

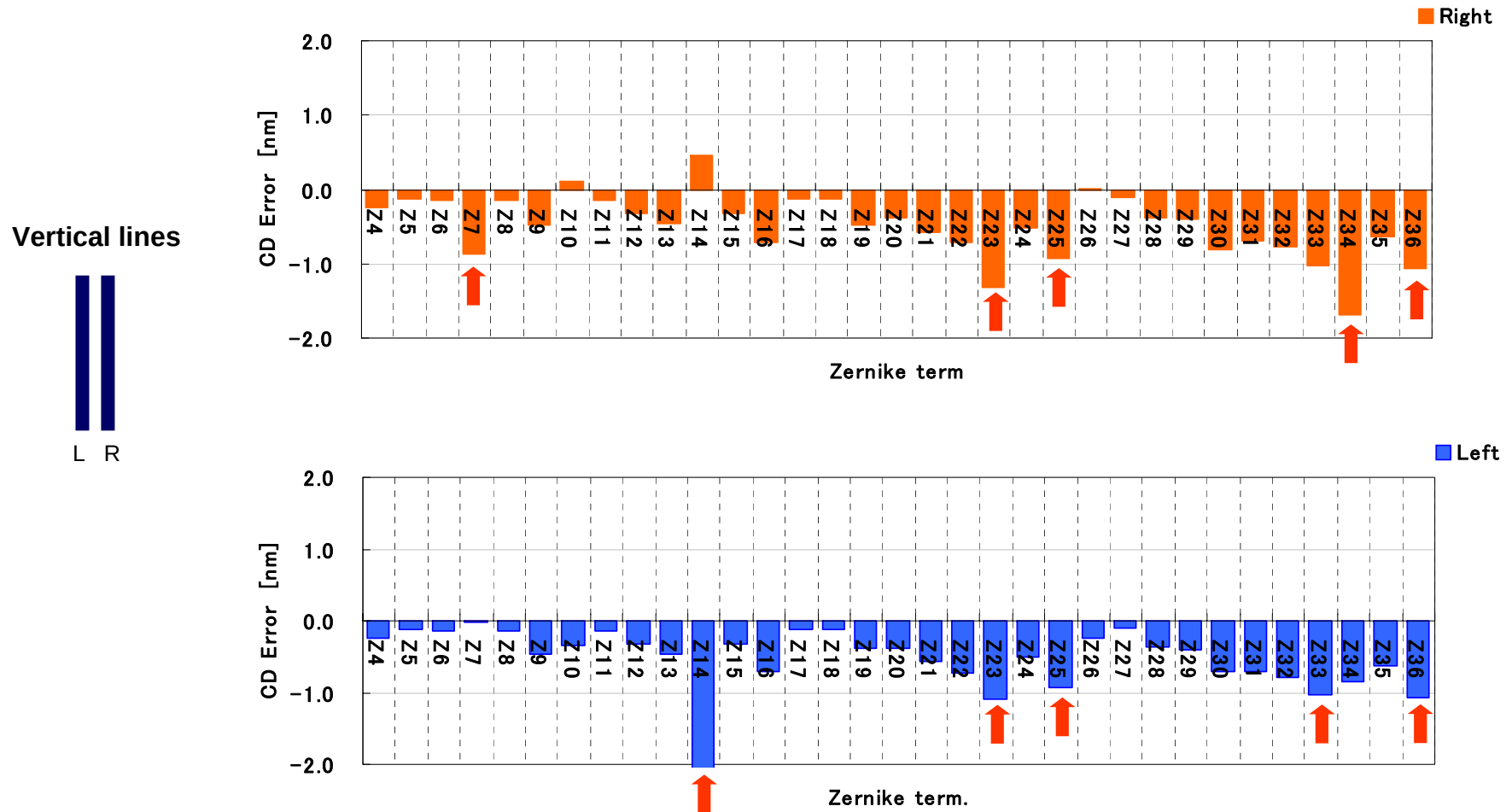
The aberration to control Positional shift below 2.2 nm

	defocus	
	0	+50 nm
Left Line	30	27
Right Line	44	42

[mλ rms]

3-3. CD error

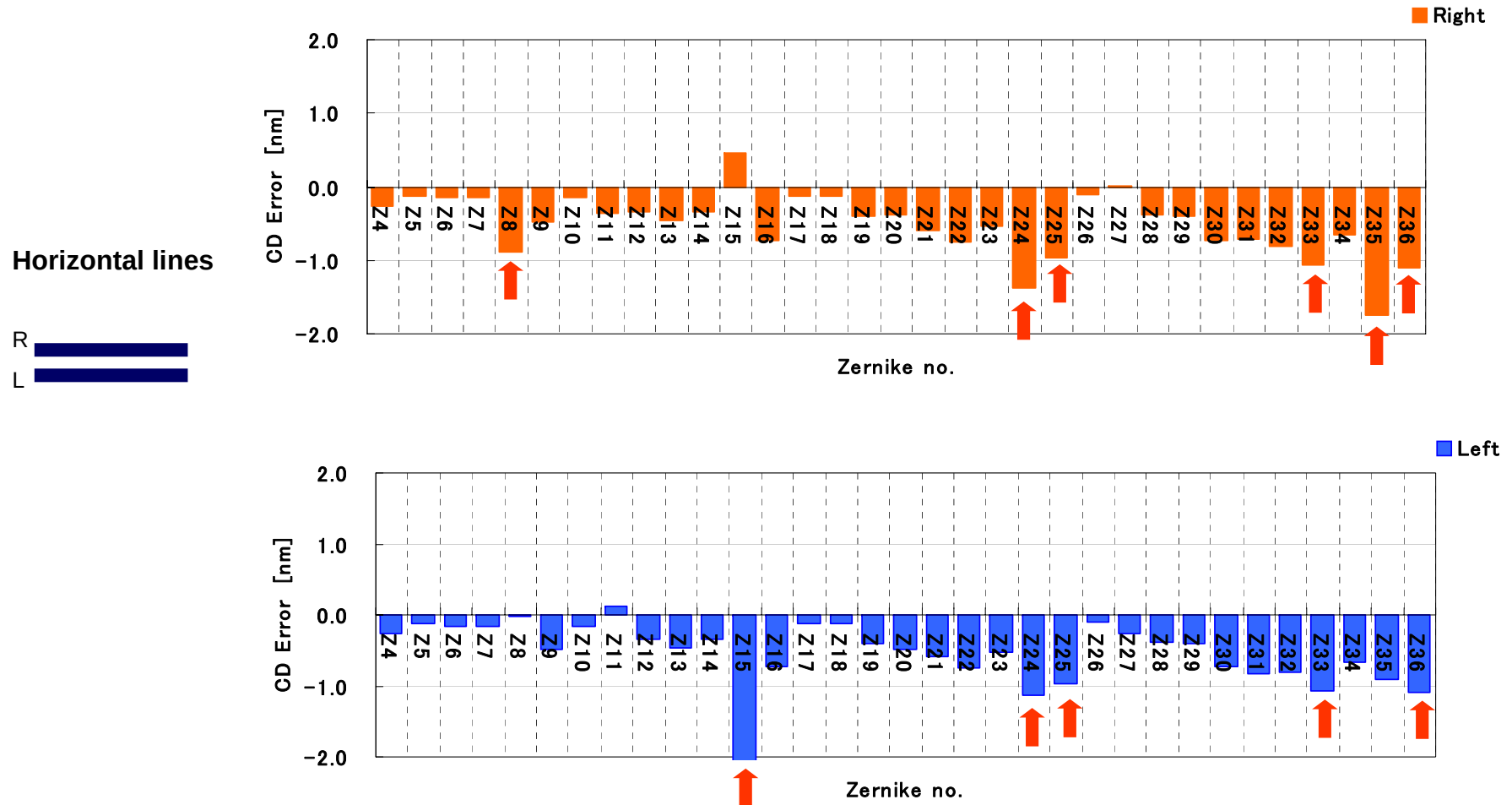
1. Zernike sensitivity (in the presence of 25 mλ rms)



Z7, Z14, Z23, Z25, Z33, Z34 and Z36 greatly affect on vertical two lines.

3-3. CD error

1. Zernike sensitivity (in the presence of 25mλ rms)

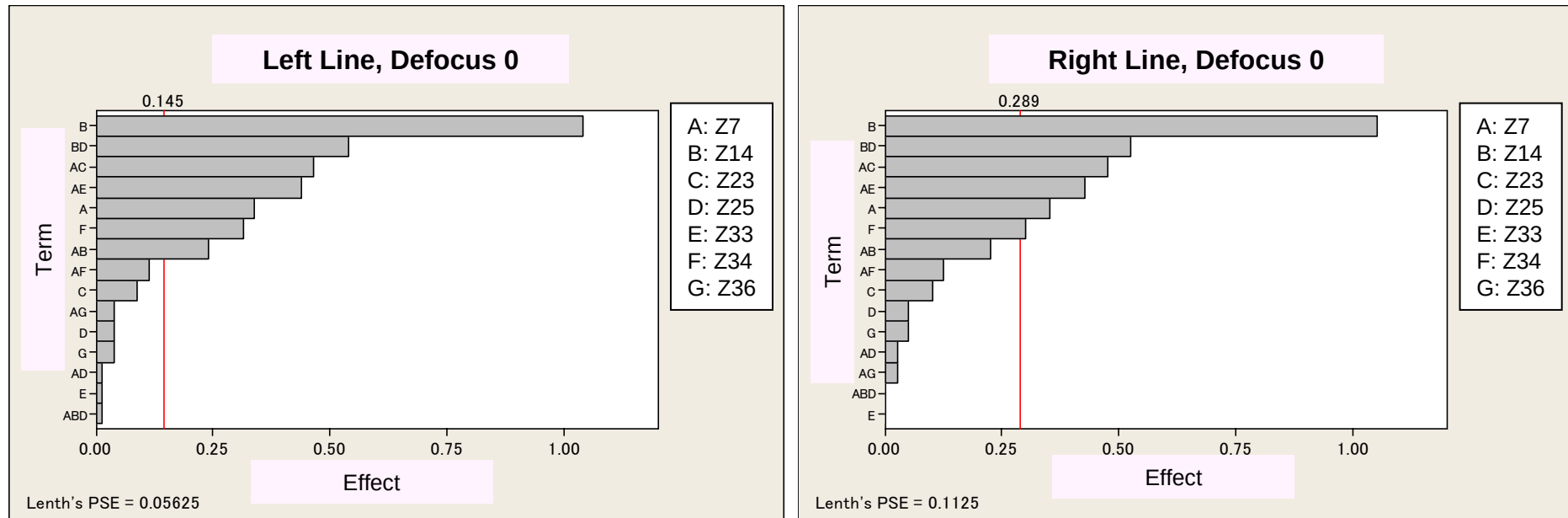


Z8, Z15, Z24, Z25, Z33, Z35 and Z36 greatly affect on vertical two lines.

3-3. CD error

2. Calculated Effectiveness of each term

Pareto Chart of the Effects



Z14 is most effective term.

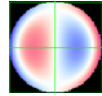
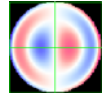
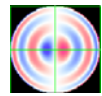
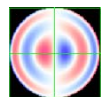
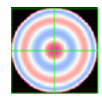
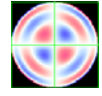
In addition, there are alternately effects between Z14 and Z25, Z7 and Z23, Z7 and Z33, Z7 and Z14.

$$\text{Total CD accuracy} \doteq B \cdot a_{14} + BD \cdot a_{14} a_{25} + AC \cdot a_7 a_{23} + AE \cdot a_7 a_{33} + A \cdot a_7 + F \cdot a_{34} + AB \cdot a_7 a_{14} + \text{constant}$$

3-3. CD error

3. Effective Zernike terms

Direction: Vertical Line

effects	terms	function	pupil image	aberration name
Independently	Z7	$\sqrt{8} (3\rho^3 - 2\rho) \cos\theta$		3 th order x-coma
	Z14	$\sqrt{12} (10\rho^5 - 12\rho^3 + 3\rho) \cos\theta$		5 th order x-coma
	Z34	$\sqrt{20} (126\rho^8 - 280\rho^6 + 210\rho^4 - 60\rho^2 + 5) \rho \cos\theta$		8 th order x-coma
alternately	Z23	$\sqrt{16} (35\rho^7 - 60\rho^5 + 30\rho^3 + 4\rho) \cos\theta$		7 th order x-coma
	Z25	$\sqrt{9} (70\rho^8 - 140\rho^6 + 90\rho^4 - 20\rho^2 + 1)$		7 th order Spherical
	Z33	$\sqrt{18} (56\rho^6 - 105\rho^4 + 60\rho^2 - 10) \rho^2 \sin 2\theta$		7 th order 45 deg. astigmatism

The greatly affective aberrations on CD error are **Coma**.

3-3. CD error

3. Effective Zernike terms

Direction: Horizontal Line

effects	terms	function	pupil image	aberration name
Independently	Z8	$\sqrt{8} (3\rho^3 - 2\rho)\sin\theta$		3 th order y-coma
	Z15	$\sqrt{12} (10\rho^5 - 12\rho^3 + 3\rho)\sin\theta$		5 th order y-coma
	Z35	$\sqrt{20} (126\rho^8 - 280\rho^6 + 210\rho^4 - 60\rho^2 + 5) \rho \sin\theta$		8 th order y-coma
alternately	Z24	$\sqrt{16} (35\rho^7 - 60\rho^5 + 30\rho^3 + 4\rho)\sin\theta$		7 th order y-coma
	Z25	$\sqrt{9} (70\rho^8 - 140\rho^6 + 90\rho^4 - 20\rho^2 + 1)$		7 th order Spherical
	Z33	$\sqrt{18} (56\rho^6 - 105\rho^4 + 60\rho^2 - 10) \rho^2 \sin 2\theta$		7 th order 45 deg. astigmatism

The greatly affective aberrations on CD error are **Coma**.

3-3. CD error

4. Results

Coefficient table

Term		Left Line		Right Line	
		defocus		defocus	
vertical	horizontal	0	+50 nm	0	+50 nm
A(Z7)	A(Z8)	0.0169	0.0207	-0.0175	-0.0213
B(Z14)	B(Z15)	-0.0519	-0.0544	0.0525	0.055
F(Z34)	F(Z35)	0.0156	0.0156	-0.015	-0.0163
AB(Z7xZ14)	AB(Z8xZ15)	0.00119	0.00131	0.00113	0.00113
AC(Z7xZ23)	AC(Z8xZ24)	0.00231	0.00131	0.00238	0.0025
AE(Z7xZ33)	AE(Z8xZ33)	0.00219	0.00131	0.00213	0.00213
BD(Z14xZ25)	BD(Z15xZ25)	0.00269	0.00306	0.00263	0.0025
Constant	Constant	-1.0688	-1.619	-1.063	-1.625

The aberration to control CD error below 2.2 nm

	defocus	
	0	+50 nm
Left Line	137	63
Right Line	32	24

[mλ rms]

4. Comparison of estimated aberrations

The permissible amounts of aberration to form 22 nm two-lines

CD difference		Positional shift			CD error		
defocus			defocus			defocus	
0	+50nm		0	+50 nm		0	+50 nm
25	24	Left Line	30	27	Left Line	137	63
		Right Line	44	42	Right Line	32	24

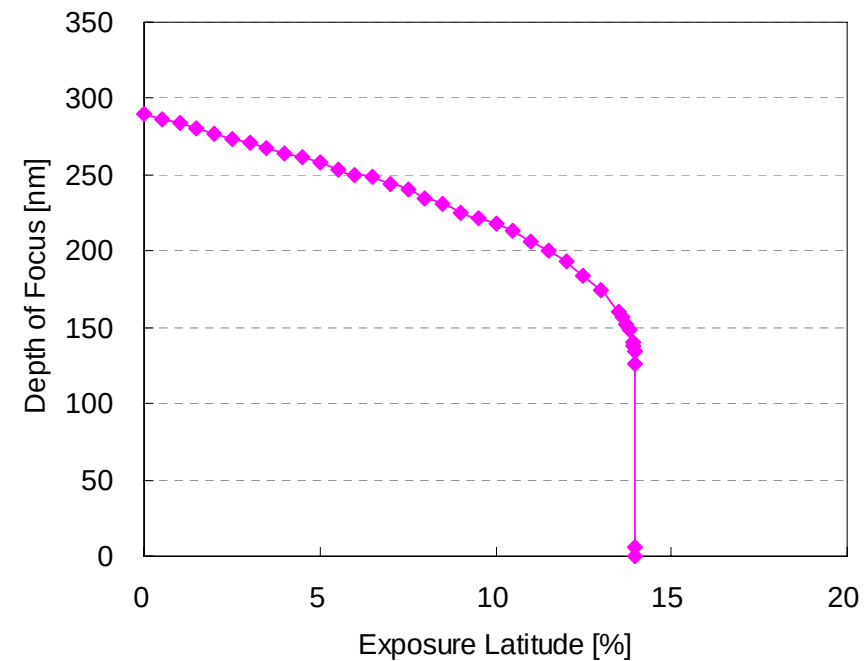
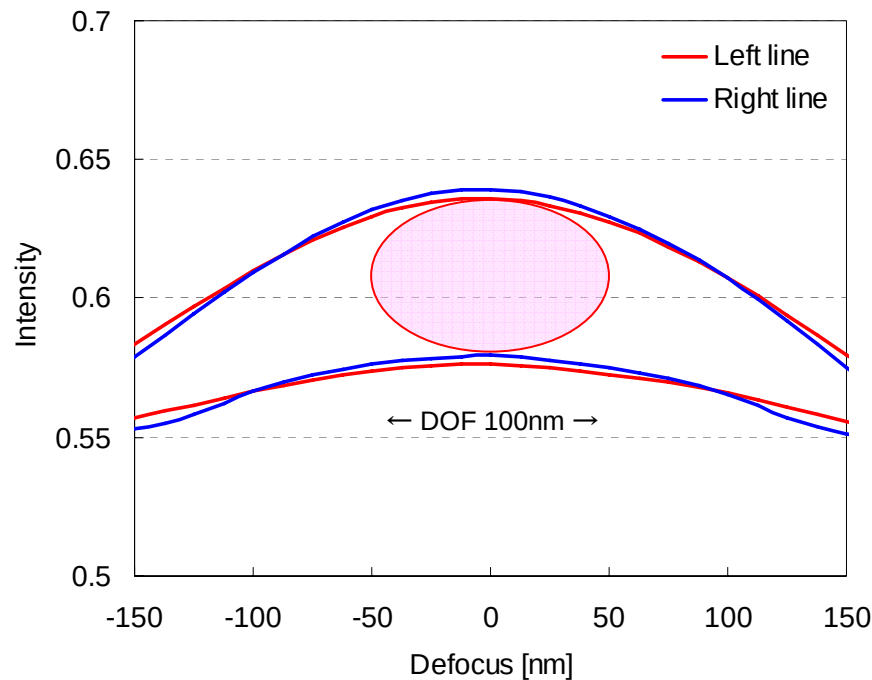
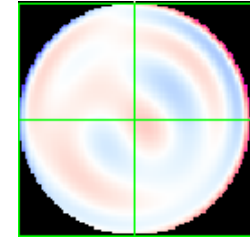
[mλ rms]

CD difference and CD error needs severe aberration conditions. Vertical lines and horizontal lines needs 24 mλ rms respectively. The aberration specification to 22 nm-node-dual gates estimated as follows.

$$\begin{aligned}
 \Delta\Phi_{rms} &= \sqrt{\sum_{j>1} C_j^2} \\
 &= \sqrt{24^2 + 24^2} = \mathbf{34\ m\lambda\ (0.46\ nm\ rms)}
 \end{aligned}$$

5. Process Window Calculation

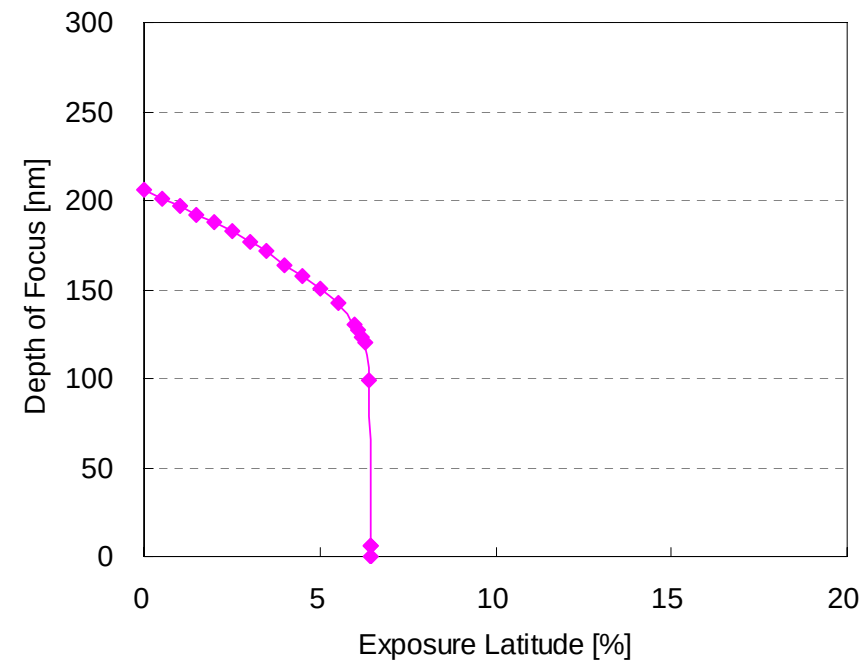
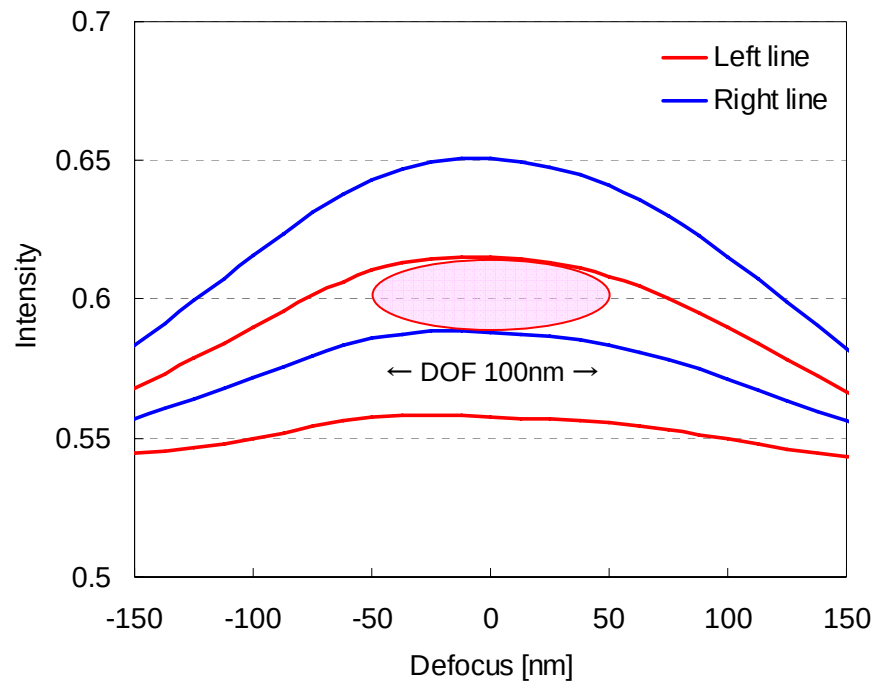
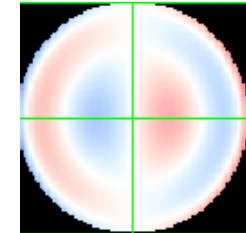
5-1. Process window of vertical lines in the presence of $24\text{ m}\lambda$ aberration evenly allocates Z7, Z14, Z23, Z25, Z33 and Z34.



If the aberration is $24\text{ m}\lambda$ (to vertical lines), an enough lithography margin can be taken for 22 nm-dual gate.

5. Process Window Calculation

5-2. Process window of vertical lines in the worst case.
All $24\text{ m}\lambda$ aberration allocates to Z14.



If the aberration is $24\text{ m}\lambda$ (to vertical lines), lithography margin of 6 % or more can be expected even in the worst case.

6. Conclusions

- We have studied about the aberration specification of 1st generation EUV tool to form 22 nm dual gates.
 - ✓ Effective Zernike terms to CD difference are coma.
 - ✓ Effective Zernike terms to positional shift are coma and 3-foil.
 - ✓ There are interaction effects of coma and spherical on CD error.
 - ✓ The aberration to form 22 nm dual gate pattern is below 34 mλ (0.46 nm rms).

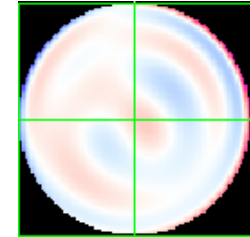
Vertical	Horizontal
24 mλ	24 mλ
34 mλ (0.46 nm rms)	

- It was confirmed to be able to take lithography margin of 22 nm dual gates in the presence of the above aberration.
- The aberration specification of 1st generation EUV tool should be settled within the above value.

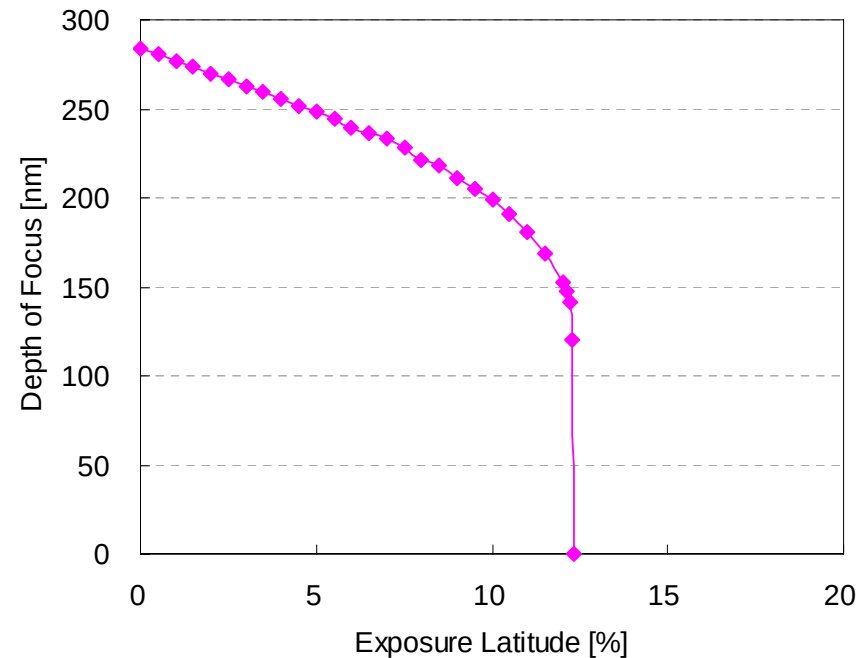
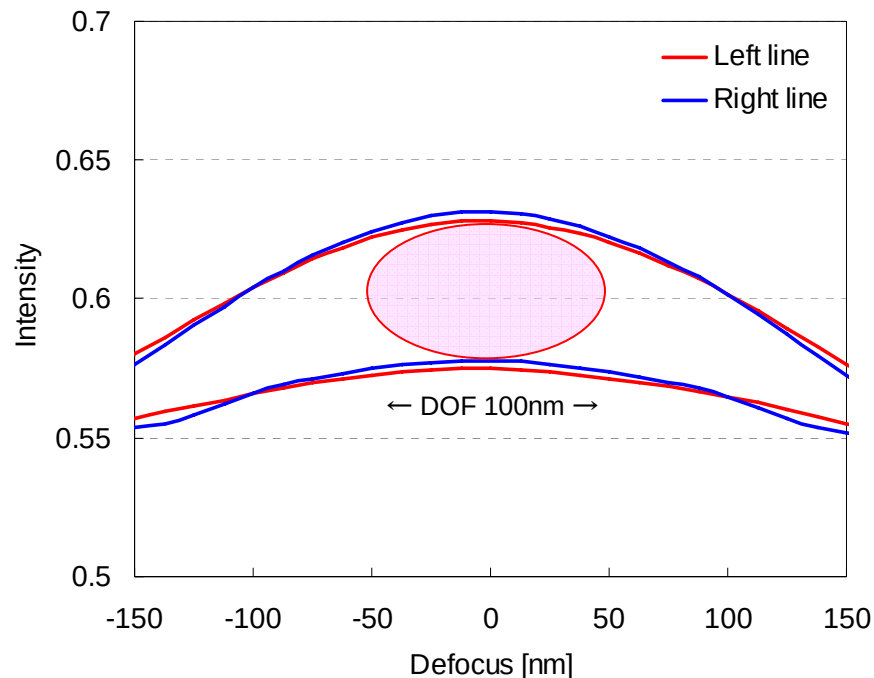
Appendix

Process Window Calculation with ΔL

1. Process window of vertical lines in the presence of 23 m λ aberration evenly allocates Z7, Z14, Z23, Z25, Z33 and Z34.



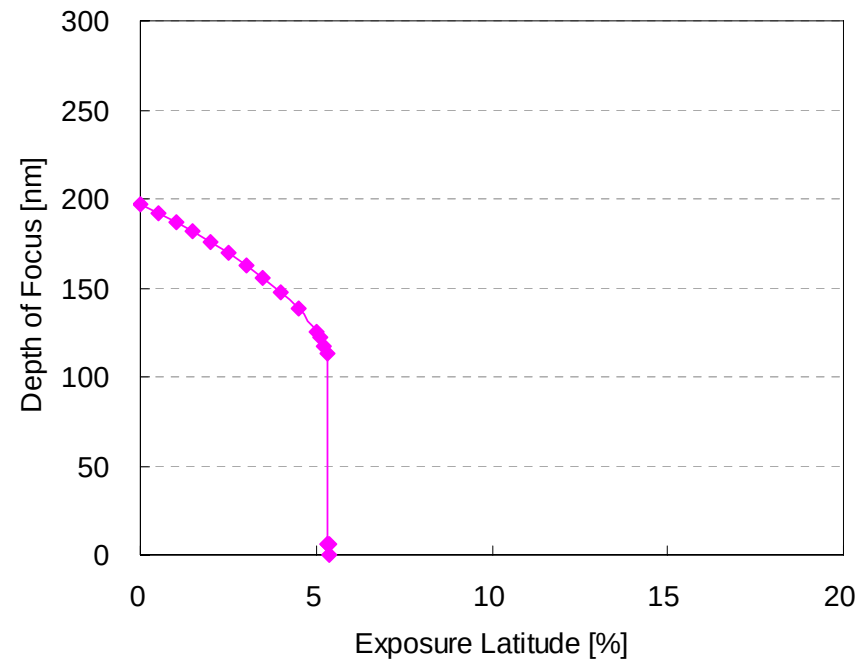
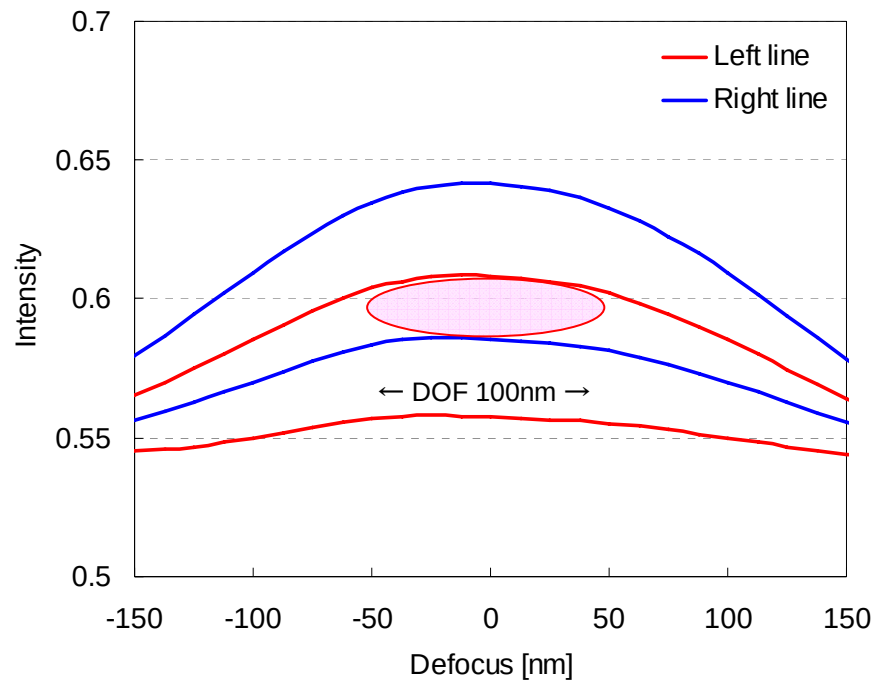
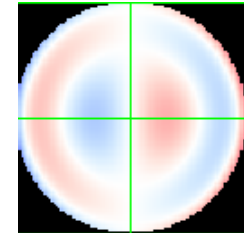
The process factor $\Delta L = 5$ nm



Process Window Calculation with ΔL

1. Process window of vertical lines in worst case.
All 24 $m\lambda$ aberration allocates to Z14.

The process factor $\Delta L = 5 \text{ nm}$



Aerial image intensity contours for 22nm dual gates

